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# MBE GROWTH OF NITRIDE-ARSENIDES FOR LONG WAVELENGTH OPTO-ELECTRONICS



MBE growth of Nitride-Arsenides for long wavelength opto-electronics  
1.3 um emission and absorption on GaAs substrates using GaInNAs. Optimization of material quality



Condition: New. Publisher/Verlag: LAP Lambert Academic Publishing | 1.3 um emission and absorption on GaAs substrates using GaInNAs. Optimization of material quality | To enable devices operating at 1.3 um on GaAs, MBE growth of a new III-V material formed by adding small amounts of nitrogen to InGaAs was developed. The growth of GaInNAs is complicated by the divergent properties of the alloy constituents and the difficulty of generating a reactive nitrogen species. To avoid phase segregation, nitride-arsenides must be...

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- Authored by Spruytte, Sylvia
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